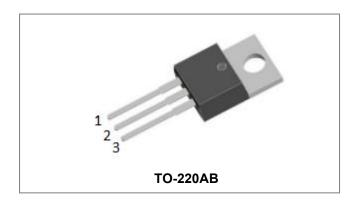


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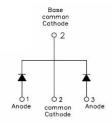
# SDUR2020CTA ULTRAFAST RECTIFIER



## **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

# **Circuit Diagram**



## **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## Maximum Ratings(at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=133°C, In DC	10(Per Leg) 20(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	96	А

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25°C	0.95	1.05	V
	V <sub>F2</sub>	@ 10A, Pulse, T <sub>J</sub> = 125°C	0.83	0.85	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	0.3	10	μA
	I <sub>R2</sub>	$@V_R = rated V_R$ $T_J = 125^{\circ}C$	51	500	uA
Reverse Recovery Time(Per Leg)	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	29	35	ns

<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%

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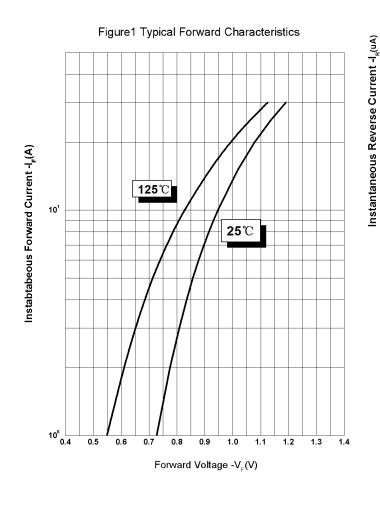


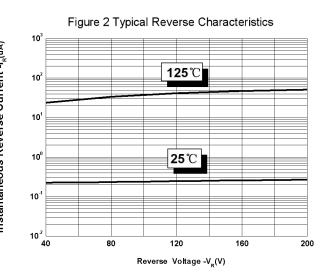


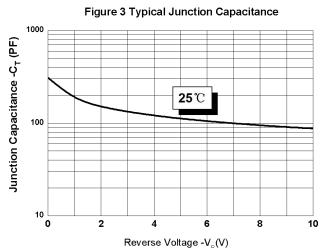
# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	°C
Storage Temperature	$T_{stg}$	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	1.6	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

# **Ratings and Characteristics Curves**







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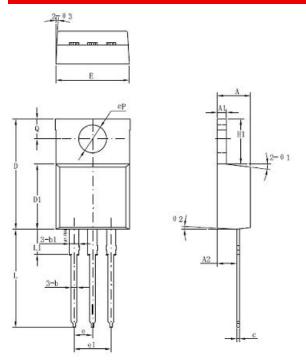


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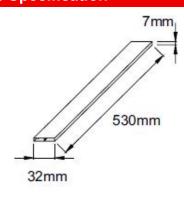


## **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters				
	Min	Typical	Max		
Α	3.56	-	4.83		
A1	0.51	-	1.40		
A2	2.03	-	2.92		
b	0.38	-	1.02		
b1	1.14	-	1.78		
С	0.31	-	0.61		
D	14.22	-	16.51		
D1	8.38	-	9.42		
E	9.65	-	10.67		
е	-	2.54	-		
e1	-	5.08	-		
H1	5.84	-	6.86		
L	12.70	-	14.73		
L1	-	-	6.35		
ФР	-	3.56	-		
Q	2.54	-	3.43		

# **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type 20 = Forward Current (20A) 20 = Reverse Voltage(200V) CTA = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

# **Ordering Information**

Device	Package	Shipping	
SDUR2020CTA	TO-220AB (Pb-Free)	50 pcs/ tube	

- China Germany Korea Singapore United States
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## SDUR2020CTA



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